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MJE180/181/182

Low Power Audio Amplifier Low Current High Speed Switching Applications



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage : MJE180	60	V
	: MJE181	80	V
	: MJE182	100	V
V _{CEO}	Collector-Emitter Voltage : MJE180	40	V
	: MJE181	60	V
	: MJE182	80	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current (DC)	3	Α
I _{CP}	Collector Current (Pulse)	6	Α
I _B	Base Current	1	Α
P _C	Collector Dissipation (T _a =25°C)	1.5	W
P _C	Collector Dissipation (T _C =25°C)	12.5	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CEO}	Collector -Emitter Breakdown Voltage				
	: MJE180	$I_C = 10 \text{mA}, I_B = 0$	40		V
	: MJE181		60		V
	: MJE182		80		V
I _{CBO}	Collector Cut-off Current : MJE180	$V_{CB} = 60 \text{ V}, I_{B} = 0$		0.1	μΑ
	: MJE181	$V_{CB} = 80V, I_{E} = 0$		0.1	μΑ
	: MJE182	$V_{CB} = 100V, I_{E} = 0$		0.1	μΑ
	: MJE180	$V_{CB} = 60V, I_{E} = 0 @ T_{C} = 150^{\circ}C$		0.1	mA
	: MJE181	$V_{CB} = 80V, I_{E} = 0 @ T_{C} = 150^{\circ}C$		0.1	mA
	: MJE182	$V_{CB} = 100V, I_{E} = 0 @ T_{C} = 150^{\circ}C$		0.1	mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 7V, I_{C} = 0$		0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = 1V, I_{C} = 100mA$	50	250	
		$V_{CE} = 1V, I_{C} = 500mA$	30		
		$V_{CE} = 1V, I_{C} = 1.5A$	12		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$		0.3	V
		$I_C = 1.5A, I_B = 150mA$		0.9	V
		$I_C = 3A, I_B = 600mA$		1.7	V
V _{BF} (sat)	Base-Emitter Saturation Voltage	$I_C = 1.5A, I_B = 150mA$		1.5	V
52,		$I_C = 3A$, $I_B = 600mA$		2.0	V
V _{BE} (on)	Base-Emitter ON Voltage	V _{CE} = 1V, I _C = 500mA		1.2	V
f _T	Current Gain Bandwidth Product	V _{CE} = 10V, I _C = 100mA	50		MHz
C _{ob}	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 0.1MHz$		30	pF

Typical Characteristics

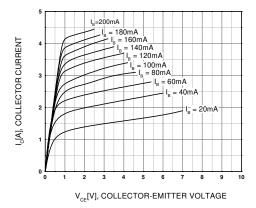


Figure 1. Static Characteristic

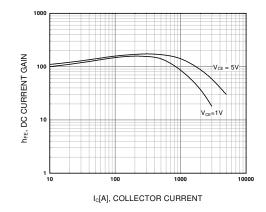


Figure 2. DC current Gain

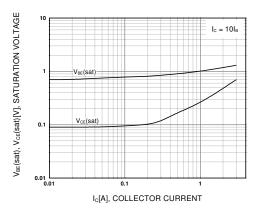


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

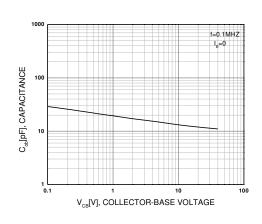


Figure 4. Collector Output Capacitance

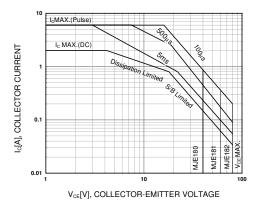


Figure 5. Safe Operating Area

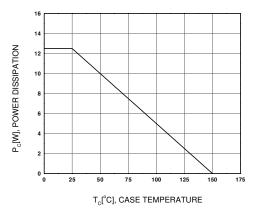
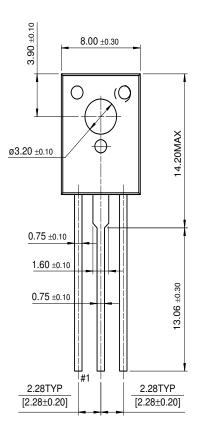


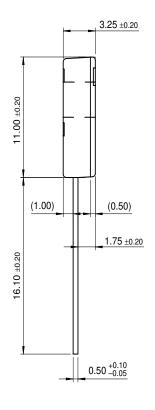
Figure 6. Power Derating

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Package Demensions

TO-126







Dimensions in Millimeters

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